SURFACE MOUNT DISPLAY

KPSC03-107

SUPER BRIGHT YELLOW

Features

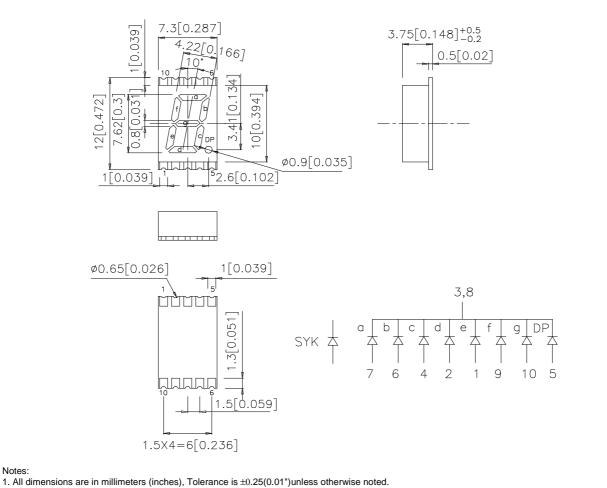
•0.3 INCH DIGIT HEIGHT.

- •LOW CURRENT OPERATION.
- •EXCELLENT CHARACTER APPEARANCE.
- •I.C. COMPATIBLE.
- •MECHANICALLY RUGGED.
- •GRAY FACE, WHITE SEGMENT.
- •PACKAGE : 1100PCS / REEL.

Description

The Super Bright Yellow source color devices are made with DH InGaAIP on GaAs substrate Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



2. Specifications are subject to change without notice.

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Selection Guide									
Part No.	Dice	Lens Type	lv (ucd) @ 10mA		Description				
			Min.	Тур.	-				
KPSC03-107	SUPER BRIGHT YELLOW (InGaAIP)	WHITE DIFFUSED	8000	35400	Common Cathode, Rt. Hand Decimal.				

Electrical / Optical Characteristics at TA=25°C

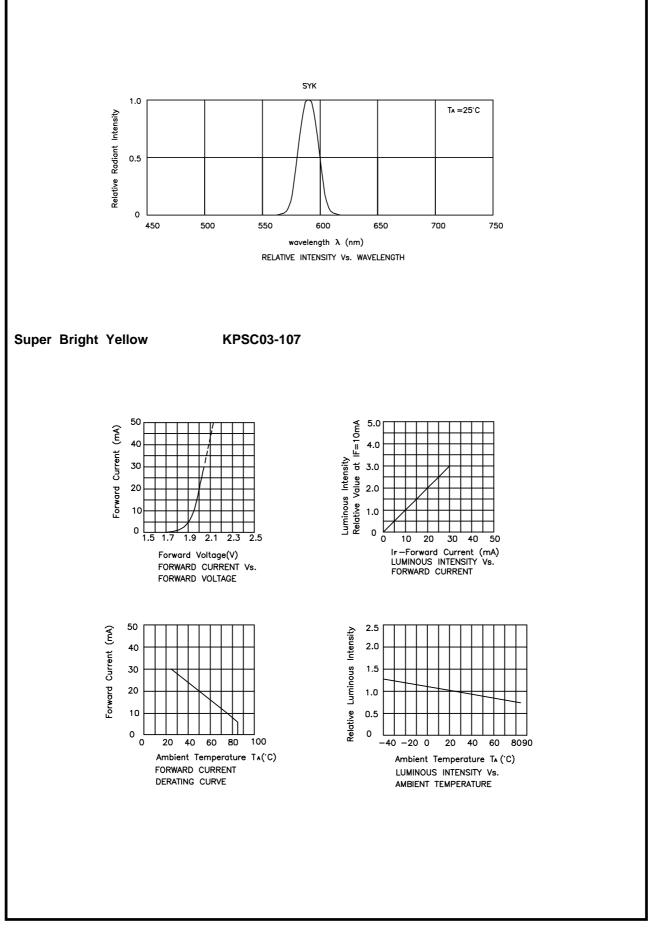
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	IF=20mA
λD	Dominant Wavelength	Super Bright Yellow	590		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	20		nm	IF=20mA
С	Capacitance	Super Bright Yellow	20		pF	VF=0V;f=1MHz
VF	Forward Voltage	Super Bright Yellow	2.0	2.5	V	IF=20mA
IR	Reverse Current	Super Bright Yellow		10	uA	VR = 5V

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Yellow	Units	
Power dissipation	125	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	175	mA	
Reverse Voltage	5	V	
Operating/Storage Temperature	-40°C To +85°C		

Note:

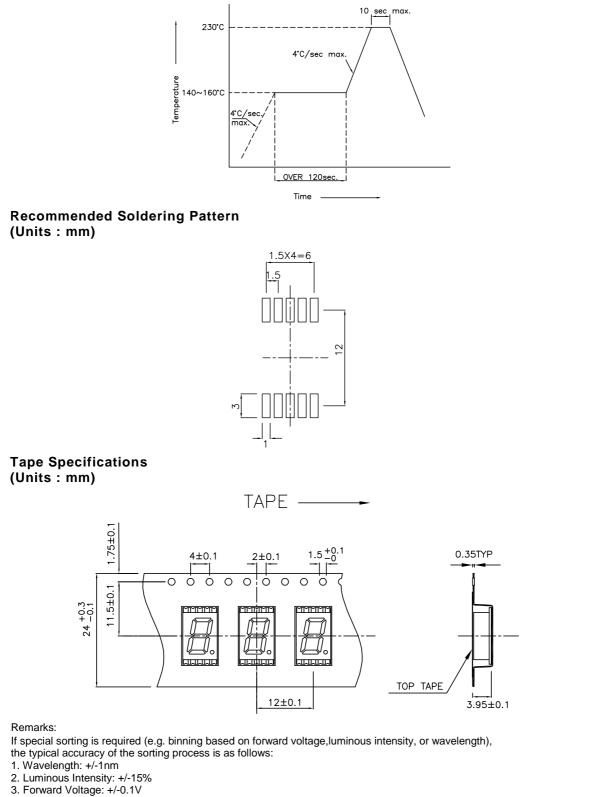
1. 1/10 Duty Cycle, 0.1ms Pulse Width.



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SMT Reflow Soldering Instructions

Number of reflow process shall be 2 times or less and cooling process to normal temperature is required between first and second soldering process.



Note: Accuracy may depend on the sorting parameters.

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